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10-15-01
Muller

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Rule 53(b) Divisional Application of:

IKEMASU et al.

Divisional of S.N. 08/876,908 filed June 16, 1997

Group Art Unit: To Be Assigned

Filed: Herewith

Examiner: To Be Assigned

For: HIGHLY INTEGRATED AND RELIABLE DRAM ADAPTED FOR SELF-ALIGNED-CONTACT (As Amended)

PRELIMINARY AMENDMENT

Commissioner for Patents
Washington, D.C. 20231

August 3, 2001

Sir:

Prior to examination, please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel claims 20-61 without prejudice or disclaimer.

Please amend claims 1 and 3 as follows:

1. (Amended) A semiconductor device comprising:

a semiconductor substrate having an uppermost insulating film;

lamination of a first conductive film of metal or metal silicide, a first insulating film, and a third insulating film made of silicon nitride laminated in this order from a lower side, the lamination being formed on or above the uppermost insulating film, and having a same pattern with a pair of side walls;